NSN 5962-01-431-4611

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Electrostatic sensitive
Inclosure Configuration:
Pin grid array
Criticality Code Justification:
Cbbl
Product Name:
Microcircuit, memory, digital, cmos, programmable logic cell array, 4200 gates
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Memory Device Type:
Pal
Special Features:
Item is selected from p/n 5962-8971302zx, cage 68994
Nuclear Hardness Critical Feature:
Hardened
Terminal Type And Quantity:
132 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0